74HC365; 74HCT365 Hex buffer/line driver; 3-state Rev. 4 – 27 January 2016

General description 1.

The 74HC365; 74HCT365 is a hex buffer/line driver with 3-state outputs controlled by the output enable inputs (OEn). A HIGH on OEn causes the outputs to assume a high impedance OFF-state. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

Features and benefits 2.

- Inverting outputs
- Input levels:
 - For 74HC365: CMOS level
 - For 74HC365: TTL level
- Complies with JEDEC standard no. 7A
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Multiple package options

Ordering information 3.

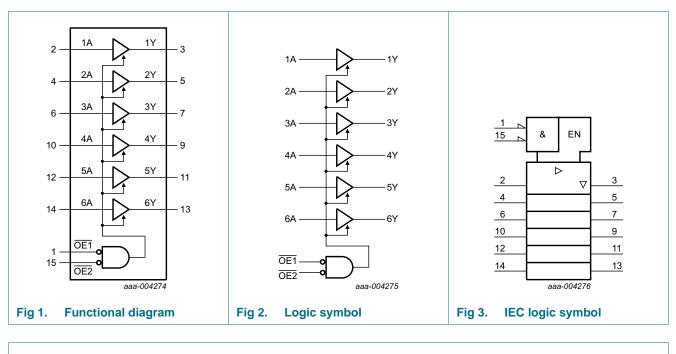
Table 1. **Ordering information**

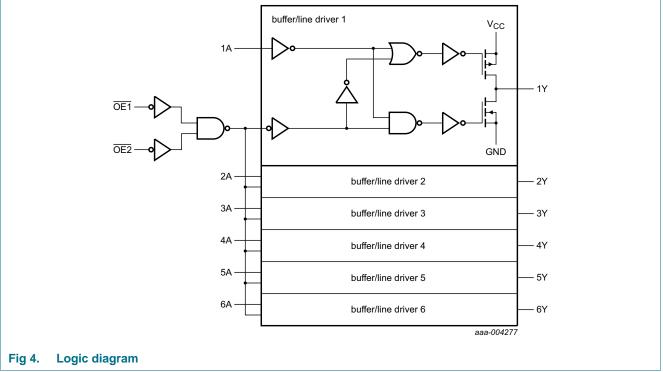
Type number	Package			
	Temperature range	Name	Description	Version
74HC365D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT365D				
74HC365DB	–40 °C to +125 °C	40 °C to +125 °C SSOP16 plastic shrink small outline package; 16 leads; body width		SOT338-1
74HCT365DB			5.3 mm	
74HC365PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body	SOT403-1
74HCT365PW			width 4.4 mm	

nexperia

Hex buffer/line driver; 3-state

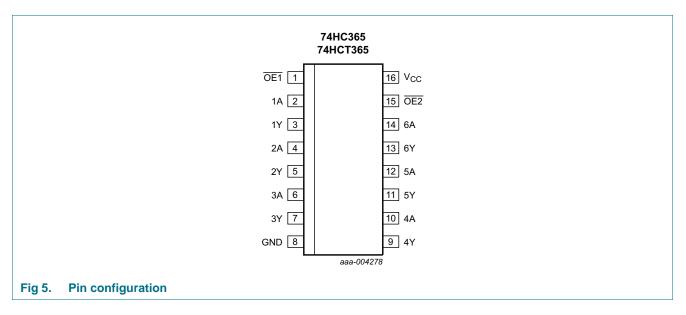
4. Functional diagram





5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
OE1	1	output enable input 1 (active LOW)
1A	2	data input 1
1Y	3	data output 1
2A	4	data input 2
2Y	5	data output 2
3A	6	data input 3
3Y	7	data output 3
GND	8	ground (0 V)
4Y	9	data output 4
4A	10	data input 4
5Y	11	data output 5
5A	12	data input 5
6Y	13	data output 6
6A	14	data input 6
OE2	15	output enable input 2 (active LOW)
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function table^[1]

Control Ir		Input	Output
OE1	OE2	nA	nY
L	L	L	L
L	L	Н	Н
Х	Н	Х	Z
Н	Х	Х	Z

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

Z = high-impedance OFF-state.

7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I} < -0.5 \text{ V or } V_{\rm I} > V_{\rm CC} + 0.5 \text{ V}$ [1]	-	±20	mA
I _{OK}	output clamping current	$V_{\rm O} < -0.5 \text{ V or } V_{\rm O} > V_{\rm CC} + 0.5 \text{ V}$ [1]	-	±20	mA
lo	output current	$V_{O} = -0.5 \text{ V to} (V_{CC} + 0.5 \text{ V})$	-	±35	mA
I _{CC}	supply current		-	70	mA
I _{GND}	ground current		-70	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	SO16 package [2]	-	500	mW
		SSOP16 package [3]	-	500	mW
		TSSOP16 package [3]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO16 packages: P_{tot} derates linearly with 8 mW/K above 70 °C.

[3] For SSOP16 and TSSOP16 packages: Ptot derates linearly with 5.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC365	5	7	4HCT36	5	Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics 74HC365

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C		I			
V _{IH}	HIGH-level input voltage	$V_{CC} = 2.0 V$	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 2.0 V$	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$	-	-	-	
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	2.0	-	V
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	V
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 6.0 \ \text{V}$	5.9	6.0	-	V
		$I_0 = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		$I_0 = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	0	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	0.16	0.26	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 6.0 \text{ V}$	-	-	±0.5	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	μA
CI	input capacitance		-	3.5	-	pF

Hex buffer/line driver; 3-state

Table 6. Static characteristics 74HC365 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +85 °C	·	I		1	1
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 2.0 V$	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		$V_{CC} = 6.0 V$	-	-	1.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	-	-	V
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	-	-	V
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		$I_0 = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	-	0.33	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0$ V;	-	-	±1.0	μΑ
l _{oz}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 6.0 \text{ V}$	-	-	±5.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	80	μA
T _{amb} = –	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{ОН}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	-	-	V
		$I_0 = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_0 = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_0 = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.2	-	-	V

Hex buffer/line driver; 3-state

Table 6. Static characteristics 74HC365 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = 20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	-	-	0.1	V
		$I_0 = 20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	-	-	0.1	V
		$I_{O} = 20 \ \mu\text{A}; \ V_{CC} = 6.0 \ \text{V}$	-	-	0.1	V
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.4	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	-	0.4	V
I _I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±1.0	μΑ
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 6.0 \text{ V}$	-	-	±10.0	μΑ
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	160	μΑ

Table 7. Static characteristics 74HCT365

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 ℃					
V _{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	4.5	-	V
		$I_{O} = -6.0 \text{ mA}$	3.98	4.32	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	0	0.1	V
		I _O = 6.0 mA	-	0.16	0.26	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	μΑ
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}$	-	-	±0.5	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	μΑ
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 2.1$ V; other inputs at V_{CC} or GND; $I_O = 0$ A				
		pins nA	-	100	360	μΑ
		pin OE1	-	100	360	μΑ
		pin OE2	-	90	324	μΑ
CI	input capacitance		-	3.5	-	pF
T _{amb} = -	-40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	-	-	V
		$I_{O} = -6.0 \text{ mA}$	3.84	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	-	0.1	V
		I _O = 6.0 mA	-	-	0.33	V
li –	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}$			±5.0	μA

Hex buffer/line driver; 3-state

Table 7. Static characteristics 74HCT365 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	80	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 2.1$ V; other inputs at V_{CC} or GND; $I_O = 0$ A				
		pins nA	-	-	450	μA
		pin OE1	-	-	450	μA
		pin OE2	-	-	405	μA
T _{amb} = -	40 °C to +125 °C					1
V _{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$		_		
	voltage	I _O = -20 μA	4.4	-	-	V
		$I_{O} = -6.0 \text{ mA}$	3.7	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	-	0.1	V
		I _O = 6.0 mA	-	-	0.4	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}$	-	-	±10.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	160	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 2.1$ V; other inputs at V_{CC} or GND; $I_O = 0$ A				
		pins nA	-	-	490	μA
		pin OE1	-	-	490	μA
		pin OE2	-	-	441	μA

10. Dynamic characteristics

Table 8. Dynamic characteristics 74HC365

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	25 °C						
pd	propagation delay	nA to nY; see <u>Figure 6</u>	<u>[1]</u>				
		V _{CC} = 2.0 V		-	30	95	ns
		V _{CC} = 4.5 V		-	11	19	ns
		V _{CC} = 5 V; C _L = 15 pF		-	9	-	ns
		V _{CC} = 6.0 V		-	9	16	ns
en	enable time	OEn to nY; see Figure 7	[2]				
		V _{CC} = 2.0 V		-	47	150	ns
		V _{CC} = 4.5 V		-	17	30	ns
		V _{CC} = 6.0 V		-	14	26	ns
dis	disable time	OEn to nY; see Figure 7	[3]				
		V _{CC} = 2.0 V		-	61	150	ns
		V _{CC} = 4.5 V		-	22	30	ns
		V _{CC} = 6.0 V		-	18	26	ns
t	transition time	see Figure 6	[4]				
		V _{CC} = 2.0 V		-	14	60	ns
		V _{CC} = 4.5 V		-	5	12	ns
		V _{CC} = 6.0 V		-	4	10	ns
C _{PD}	power dissipation capacitance	per buffer; $V_I = GND$ to V_{CC}	[5]	-	40	-	pF
T _{amb} = -	-40 °C to +85 °C						
pd	propagation delay	nA to nY; see Figure 6	<u>[1]</u>				
		V _{CC} = 2.0 V		-	-	120	ns
		V _{CC} = 4.5 V		-	-	24	ns
		V _{CC} = 6.0 V		-	-	20	ns
en	enable time	OEn to nY; see Figure 7	[2]				
		V _{CC} = 2.0 V		-	-	190	ns
		V _{CC} = 4.5 V		-	-	38	ns
		V _{CC} = 6.0 V		-	-	33	ns
dis	disable time	OEn to nY; see Figure 7	[3]				
		V _{CC} = 2.0 V		-	-	190	ns
		V _{CC} = 4.5 V		-	-	38	ns
		V _{CC} = 6.0 V		-	-	33	ns
t	transition time	see Figure 6	<u>[4]</u>				
		V _{CC} = 2.0 V		-	-	75	ns
		V _{CC} = 4.5 V		-	-	15	ns
		V _{CC} = 6.0 V		-	-	13	ns

Hex buffer/line driver; 3-state

Table 8. Dynamic characteristics 74HC365 ... continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = -	40 °C to +125 °C					1	
t _{pd}	propagation delay	nA to nY; see Figure 6	<u>[1]</u>				
		$V_{CC} = 2.0 V$		-	-	145	ns
		$V_{CC} = 4.5 V$		-	-	29	ns
		$V_{CC} = 6.0 V$		-	-	25	ns
t _{en}	enable time	OEn to nY; see Figure 7	[2]				
		$V_{CC} = 2.0 V$		-	-	225	ns
		$V_{CC} = 4.5 V$		-	-	45	ns
		$V_{CC} = 6.0 V$		-	-	38	ns
t _{dis}	disable time	OEn to nY; see Figure 7	[3]				
		$V_{CC} = 2.0 V$		-	-	225	ns
		$V_{CC} = 4.5 V$		-	-	45	ns
		$V_{CC} = 6.0 V$		-	-	38	ns
t _t	transition time	see Figure 6	<u>[4]</u>				
		$V_{CC} = 2.0 V$		-	-	90	ns
		$V_{CC} = 4.5 V$		-	-	18	ns
		V _{CC} = 6.0 V		-	-	15	ns

 $\label{eq:tpd} [1] \quad t_{pd} \text{ is the same as } t_{PHL} \text{ and } t_{PLH}.$

 $\label{eq:tensor} \begin{tabular}{c} [2] & t_{en} \mbox{ is the same as } t_{PZH} \mbox{ and } t_{PZL}. \end{tabular}$

 $[3] \quad t_{\text{dis}} \text{ is the same as } t_{\text{PHZ}} \text{ and } t_{\text{PLZ}}.$

 $\label{eq:ttime_time} [4] \quad t_t \text{ is the same as } t_{THL} \text{ and } t_{TLH}.$

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $\mathsf{P}_{\mathsf{D}} = \mathsf{C}_{\mathsf{P}\mathsf{D}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}^2 \times \mathsf{f}_i \times \mathsf{N} + \sum (\mathsf{C}_{\mathsf{L}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}^2 \times \mathsf{f}_o) \text{ where:}$

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

Table 9. Dynamic characteristics 74HCT365

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	5 °C						
t _{pd}	propagation delay	nA to nY; see Figure 6	<u>[1]</u>				
		$V_{CC} = 4.5 V$		-	14	25	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	11	-	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	[2]	-	18	35	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	<u>[3]</u>	-	23	35	ns
t _t	transition time	$V_{CC} = 4.5 V$; see <u>Figure 6</u>	<u>[4]</u>	-	5	12	ns
C _{PD}	power dissipation capacitance	per buffer; $V_I = GND$ to $(V_{CC} - 1.5 V)$	<u>[5]</u>	-	40	-	pF

Hex buffer/line driver; 3-state

Table 9. Dynamic characteristics 74HCT365 ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = -	40 °C to +85 °C						
t _{pd}	propagation delay	nA to nY; V_{CC} = 4.5 V; see Figure 6	<u>[1]</u>	-	-	31	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	[2]	-	-	44	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	[3]	-	-	44	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Figure 6</u>	<u>[4]</u>	-	-	15	ns
T _{amb} =	40 °C to +125 °C						_
t _{pd}	propagation delay	nA to nY; V_{CC} = 4.5 V; see Figure 6	<u>[1]</u>	-	-	38	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	[2]	-	-	53	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	[3]	-	-	53	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Figure 6</u>	<u>[4]</u>	-	-	18	ns

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

- [2] t_{en} is the same as t_{PZH} and t_{PZL} .
- [3] t_{dis} is the same as t_{PHZ} and t_{PLZ} .
- $\label{eq:ttime_time} [4] \quad t_t \text{ is the same as } t_{THL} \text{ and } t_{TLH}.$

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \sum (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 $f_i = input frequency in MHz;$

 $f_o = output frequency in MHz;$

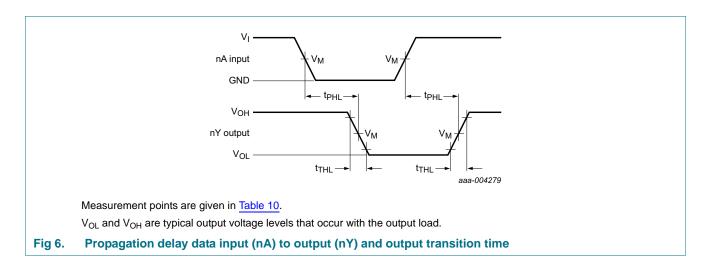
 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

11. Waveforms



Hex buffer/line driver; 3-state

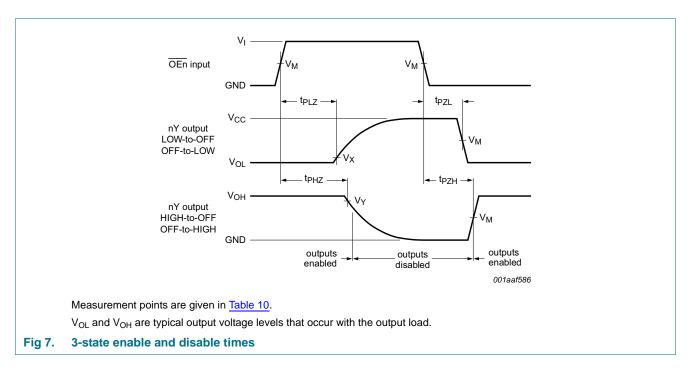


Table 10.Measurement points

Туре	Input	Output		
	V _M	V _M	V _X	V _Y
74HC365	0.5V _{CC}	0.5V _{CC}	$0.1 \times V_{CC}$	$0.9 imes V_{CC}$
74HCT365	1.3 V	1.3 V	$0.1 \times V_{CC}$	$0.9 imes V_{CC}$

Hex buffer/line driver; 3-state

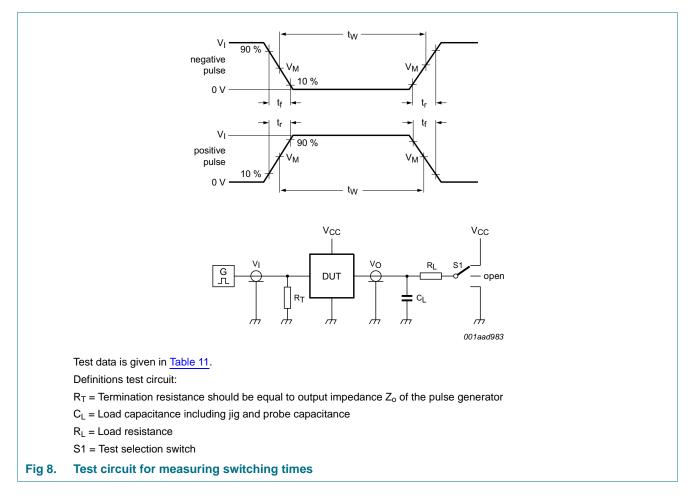


Table 11. Test data

Туре	Input		Load		S1 position		
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
74HC365	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}
74HCT365	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}

Hex buffer/line driver; 3-state

12. Package outline

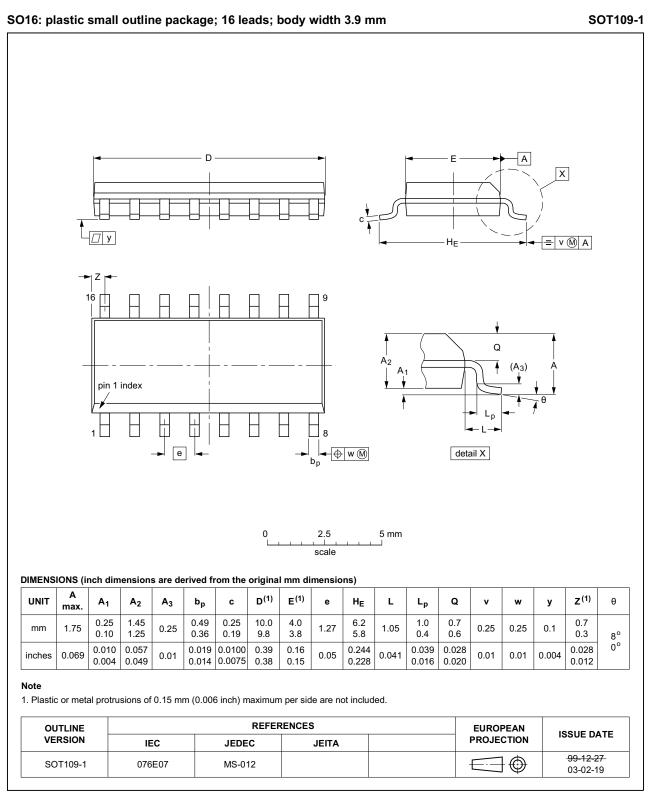


Fig 9. Package outline SOT109-1 (SO16)

Hex buffer/line driver; 3-state

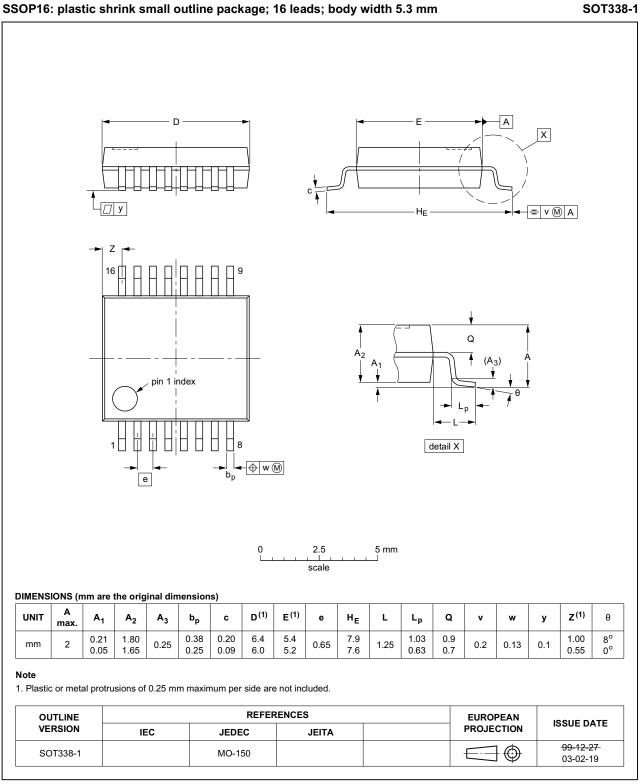


Fig 10. Package outline SOT338-1 (SSOP16)

Hex buffer/line driver; 3-state

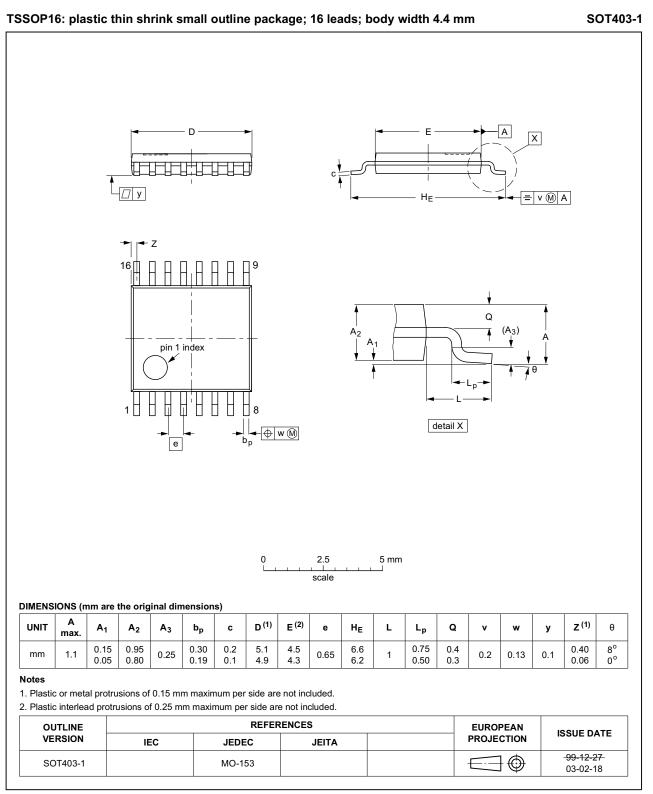


Fig 11. Package outline SOT403-1 (TSSOP16)

74HC_HCT365

Product data sheet

13. Abbreviations

Table 12. Abbreviations				
Acronym	Description			
CMOS	Complementary Metal Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MM	Machine Model			

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT365 v.4	20160127	Product data sheet	-	74HC_HCT365 v.3		
Modifications:	Type numbers	• Type numbers 74HC365N and 74HCT365N (SOT38-4) removed.				
74HC_HCT365 v.3	20120905	Product data sheet	-	74HC_HCT365_CNV v.2		
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 			th the new identity		
	 Legal texts have been adapted to the new company name where appropriate. 					
74HC_HCT365_CNV v.2	19970829	Product specification	-	-		

15. Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Hex buffer/line driver; 3-state

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